

Band Structure and Fermi Surface of an Extremely Overdoped Iron-Based Superconductor KFe_2As_2

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We have performed high-resolution angle-resolved photoemission spectroscopy on heavily overdoped KFe_2As_2 (transition temperature $T_c = 3$ K). We observed several renormalized bands near the Fermi level with a renormalization factor of 2-4. While the Fermi surface (FS) around the Brillouin-zone center is qualitatively similar to that of optimally-doped $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ ($x = 0.4$; $T_c = 37$ K), the FS topology around the zone corner (M point) is markedly different: the two electron FS pockets are completely absent due to excess of hole doping. This result indicates that the electronic states around the M point play an important role in the high- T_c superconductivity of $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ and suggests that the interband scattering via the antiferromagnetic wave vector essentially controls the T_c value in the overdoped region.

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The discovery of superconductivity at 26 K [1] (43 K under high pressure [2]) in $\text{LaFeAsO}_{1-x}\text{F}_x$, has triggered intensive researches on the high-temperature (T_c) superconductivity of iron (Fe) pnictides. The T_c value has already exceeded 55 K by replacing La atom with other rare-earth atoms or by introducing oxygen vacancies[3, 4], opening a new avenue for high- T_c material research beside cuprates. Remarkable aspects of the FeAs-based superconductors are (i) electrons in the Fe orbitals, generally believed to be the foe, indeed play an essential role in superconductivity[1, 5, 6], (ii) non-doped parent compounds commonly exhibit a collinear antiferromagnetic (AF) spin density wave (SDW)[7, 8], and (iii) the superconductivity emerges either by the hole or electron doping into the parent compounds[1, 9]. To elucidate the mechanism of high- T_c superconductivity in terms of the electronic structure, angle-resolved photoemission spectroscopy (ARPES) has been performed on both hole- and electron-doped compounds in the optimally- and non(under)-doped region [6, 10, 11, 12, 13, 14, 15, 16, 17] and it clarified key features on the band structure, the FS topology, and the superconducting gap. On the other hand, little is known about the electronic states in the overdoped region. As demonstrated by electrical resistivity measurements, the T_c value of the hole-doped $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ monotonically decreases from the optimally-doped region ($T_c = 37$ K) upon hole doping but does not completely disappear even at the highest doping level ($x = 1.0$; $T_c \sim 3$ K)[18, 19], unlike the overdoped cuprates. The resistivity does not show SDW-related anomalies in the overdoped region[19]. Clarifying the microscopic origin of this T_c reduction would be a key to find an essential ingredient to achieve high- T_c values

in the iron-based superconductors. It is thus of particular importance to gain insight into the band structure and the FS by performing ARPES measurements on overdoped samples and directly compare the electronic states with the optimally-doped ones for a comprehensive understanding of the high- T_c mechanism.

In this Letter, we report high-resolution ARPES results on KFe_2As_2 ($T_c = 3$ K), the overdoped limit of $\text{A}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ ($\text{A} = \text{Alkali earth metal}$; $x = 1$). We have determined the band structure near E_F and the FS topology, and compared with the results of optimally-doped $\text{Ba}_{0.6}\text{K}_{0.4}\text{Fe}_2\text{As}_2$ ($T_c = 37$ K). We demonstrate that, unlike $\text{Ba}_{0.6}\text{K}_{0.4}\text{Fe}_2\text{As}_2$, the nesting condition via the AF wave vector is not satisfied in KFe_2As_2 . We discuss the implications of the present results in terms of electron correlations and interband scattering.

High-quality single crystals of KFe_2As_2 used in this study were grown by the flux method[20]. High-resolution ARPES measurements were performed using a VG-SCIENIA SES2002 spectrometer with a high-flux discharge lamp and a toroidal grating monochromator. We used the He I α resonance line ($h\nu = 21.218$ eV) to excite photoelectrons. The energy and angular (momentum) resolutions were set at 4-10 meV and 0.2° ($0.007\text{\AA}^{-1}$), respectively. Clean surfaces for ARPES measurements were obtained by *in-situ* cleaving of crystals in a working vacuum better than 5×10^{-11} Torr. The Fermi level (E_F) of the samples was referenced to that of a gold film evaporated onto the sample substrate. Mirror-like sample surfaces were found to be stable without obvious degradation for the measurement period of 3 days.

Figure 1 shows ARPES spectra of KFe_2As_2 measured at 15 K with the He I α line along two high-symmetry

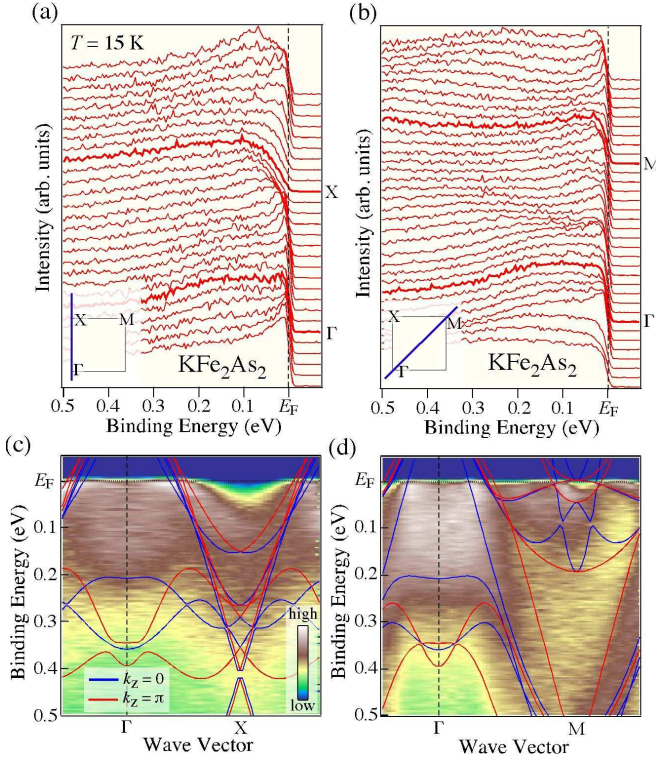


FIG. 1: (Color online) ARPES spectra near E_F of KFe_2As_2 ($T_c = 3$ K) measured at 15 K with the He I α line along two high symmetry lines (a) ΓX and (b) ΓM . (c) and (d), ARPES intensity plots as a function of wave vector and binding energy along the ΓX and ΓM lines, respectively, together with the band dispersion from the LDA calculations for $k_z = 0$ and π (blue and red curves, respectively). Calculated bands for BaFe_2As_2 [21] are shifted upward by 200 meV and then renormalized by a factor of 2.

lines (a) ΓX and (b) ΓM . In the ΓX cut (Fig. 1(a)), we find a band showing a holelike dispersion centered at the Γ point which crosses E_F midway between the Γ and X points. This band has a bottom of dispersion around 0.1 eV at the X point. In the ΓM cut (Fig. 1(b)), we observe a few less-dispersive bands crossing E_F which always stay within 0.1 eV with respect to E_F . We also observe a broad feature rapidly dispersing toward higher binding energy on approaching the M point. To see more clearly the dispersive bands, we have mapped the ARPES intensity as a function of wave vector and binding energy and show the results in Figs. 1(c) and (d) for the ΓX and ΓM directions, respectively. We also plot the band structure calculated within the local-density approximation (LDA) at $k_z = 0$ and π (blue and red curves, respectively)[21]. The calculated bands for BaFe_2As_2 are shifted upward by 0.2 eV to account for the chemical-potential shift due to hole doping, and then divided by a renormalization factor of 2. As clearly seen in Figs. 1(c) and (d), the experimentally determined band structure shows an overall agreement with the renormalized LDA calculations.

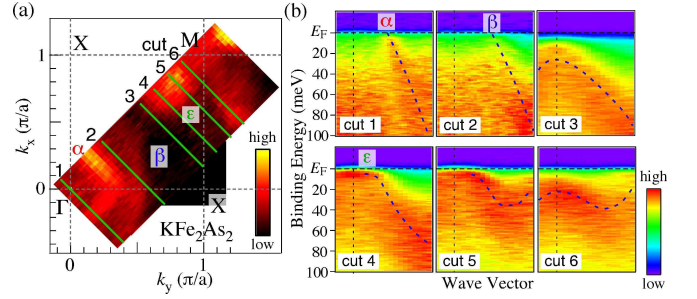


FIG. 2: (Color online) (a) ARPES-intensity plot at E_F of KFe_2As_2 as a function of the two-dimensional wave vector measured at 15 K. The intensity at E_F is obtained by integrating the spectra within ± 10 meV with respect to E_F . (b) Representative ARPES-intensity plots in the vicinity of E_F as a function of binding energy and wave vector measured along cuts 1-6 indicated by green lines in (a). Blue dashed lines are guide for eyes to trace the band dispersion. Black dashed line indicates the momentum on the ΓM line.

Especially, a highly-dispersive band in Fig. 1(d) whose energy exceeds 0.5 eV at midway between the Γ and M points is well reproduced by the renormalized calculations. We also find some differences in the energy position of bands between the experiment and the calculations, *e.g.*, the higher-energy bands at the Γ point (0.1-0.2 eV in the experiment *v.s.* 0.2-0.4 eV in the calculations), suggesting that some bands are more strongly renormalized with a renormalization factor of ~ 4 . This implies a possible orbital/momentum dependence of the electron correlation effect.

Figure 2(a) shows the ARPES-intensity plot at E_F as a function of the two-dimensional wave vector measured at 15 K. Bright areas correspond to the experimentally-determined FS. We identify two holelike FSs centered at the Γ point, where the inner one displays a stronger intensity. These FSs are also observed in $\text{Ba}_{0.6}\text{K}_{0.4}\text{Fe}_2\text{As}_2$ [6] (called K0.4 sample) and therefore ascribed to the α (inner) and β (outer) hole pockets. We also find small bright spots slightly away from the M point, called here the ϵ pockets. To clarify the topology of the ϵ FS, we plot in Fig. 2(b) the ARPES intensity in the vicinity of E_F as a function of the wave vector and binding energy for representative cuts (1-6). As seen in the cuts 3-6, the band to produce the ϵ FS is less dispersive than the α and β bands near the Γ point (cuts 1 and 2, respectively) and shows a holelike dispersion with respect to the ΓM line (black dashed line). This ϵ band crosses E_F in cuts 4 and 5, producing a small hole pocket. No evidence for the two electron pockets (γ and δ FSs) [6, 21, 22, 23, 24, 25] has been found at the M point, likely due to the excess of hole doping which lifts the band bottom of the electron pockets above E_F .

Figure 3(a) displays a direct comparison of the momentum location of k_F points between the K0.4 and K1.0 samples. As clearly visible, the volume of the α and β

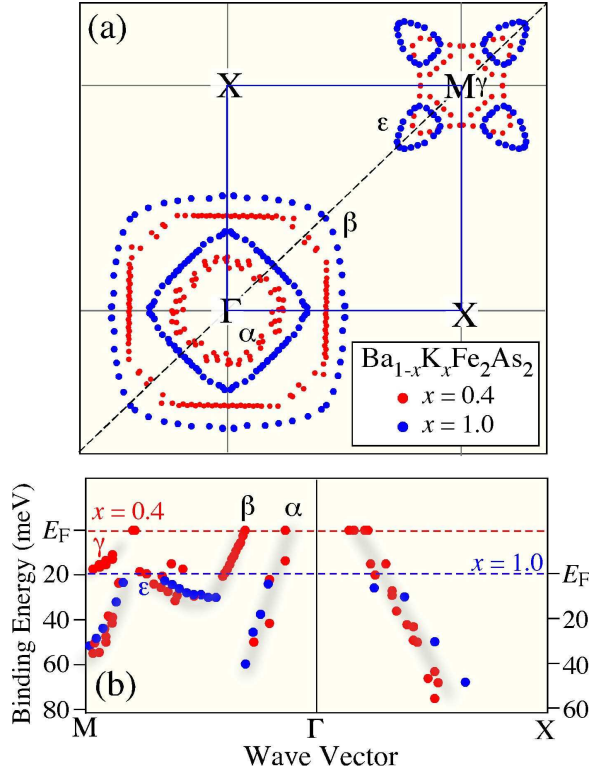


FIG. 3: (Color online) (a) Comparison of experimentally determined k_F points between overdoped KFe_2As_2 ($T_c = 3$ K) and optimally-doped $\text{Ba}_{0.6}\text{K}_{0.4}\text{Fe}_2\text{As}_2$ ($T_c = 37$ K) [6] (blue and red circles, respectively). The k_F points are symmetrized by assuming a four-fold symmetry with respect to the Γ and M points. (b) Experimental band dispersion in the vicinity of E_F for two high-symmetry lines determined by tracing the peak position of the ARPES spectra. The chemical potential of the K1.0 sample is shifted downward with respect to that of the K0.4 sample.

FSs expands due to hole doping. Indeed, the estimated volumes of these two FSs with respect to the first BZ for $x = 1.0$ are 7 and 22%, respectively, much larger than that for $x = 0.4$ (4 and 18 %, respectively [6]). By taking into account the volume of the ϵ FS (2.5 %) and the predicted degenerated β band [21] (22 %), the total hole concentration is estimated to be 1.05. This value is remarkably consistent with the doping level of $x = 1.0$, indicating the bulk nature of this measurement. We emphasize here that the FS topology at the M point is drastically different between the two doping levels since the small γ and δ electron pockets observed at $x = 0.4$ are completely absent at $x = 1.0$. This marked difference is reasonably explained by a simple energy shift due to hole doping. As shown in Fig. 3(b), the energy position of the bands in the vicinity of E_F for $x = 0.4$ and 1.0 quantitatively matches each other when we shift down the bands for $x = 1.0$ by 20-25 meV, demonstrating the applicability of a rigid-band model. This chemical potential shift is much smaller than the expected value from

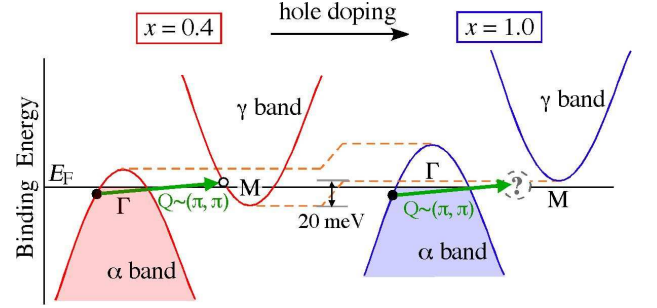


FIG. 4: (Color online) Schematic view of the interband scattering by the AF wave vector Q_{AF} between the hole and electron bands (the α and γ bands) centered at Γ and M points, respectively. The interband scattering is markedly suppressed in the overdoped region due to the absence of the electron FSs at M .

the band calculations (~ 120 meV), possibly due to the strong mass renormalization of the near- E_F bands as seen in Fig. 1. Since the bottom of the electronlike γ band for $x = 0.4$ is 18 meV below E_F , the γ band for $x = 1.0$ completely disappears in the unoccupied region by the observed chemical potential shift of 20-25 meV.

Now we discuss the present ARPES results and their implication on the pairing mechanism. As seen in the schematic band structure in Fig. 4(a), the α and γ FSs of the optimally-doped K0.4 sample are well connected by the AF wave vector $Q_{AF} = (\pi, \pi)$ in the unreconstructed zone scheme[6]. Therefore, the enhanced interband scattering via the Q_{AF} vector would promote the kinetic process of pair scattering between these two FSs by low-energy fluctuations, leading to an increase of the pairing amplitude[26, 27, 28]. This concept is supported by the observation of a superconducting-gap magnitude that is twice larger for the α and γ FSs (12 meV) as compared to the β FS (6 meV)[6]. On the other hand, in the overdoped region ($x = 1.0$), this interband scattering would diminish since the γ band is in the unoccupied side and the size of the α band increases significantly. This suggests that the interband scattering between the α and γ bands is an essential ingredient to achieve high- T_c values in iron-based superconductors. We further speculate that the β FS may not contribute deeply to the pairing mechanism in the hole-doped region since its topology and shape are quite similar between optimally- and overdoped samples whereas the T_c values are dramatically different. The opening of a small superconducting gap of the β band of the K0.4 sample [6] might be due to a proximity effect.

In conclusion, we reported ARPES results on KFe_2As_2 ($T_c = 3$ K) and determined the band dispersion near E_F and the FS topology. The experimentally determined FS consists of three types of hole pockets, two centered at the Γ point (α and β), and one around the M point (ϵ). The small γ electron pocket seen in the optimally-doped

sample is completely absent, resulting in the suppression of the $Q_{\text{AF}} = (\pi, \pi)$ interband scattering which is likely responsible for the reduction of T_c values in the over-doped region.

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